FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET NO. 58268.00368	SERIAL NO. New Cont. Appln
LIST OF REFERENCES CITED BY APPLICANT	APPLICANT Ning LI et al.	
(Use several sheets if necessary)	FILING DATE March 19, 2004	GROUP 2817

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SJM	AM	"LVDS I/O Interface of Gb/s-per-Pin Operation in 0.35-μm CMOS" by Andrea Boni, Member, IEEE, Andrea Pierazzi, and Davide Vecchi; IEEE Journal of Solid-State Circuits, Vol. 36, No. 4, April 2001; pgs. 706-711
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EXAMINER S J Mottola	DATE CONSIDERED 7-7-04

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.